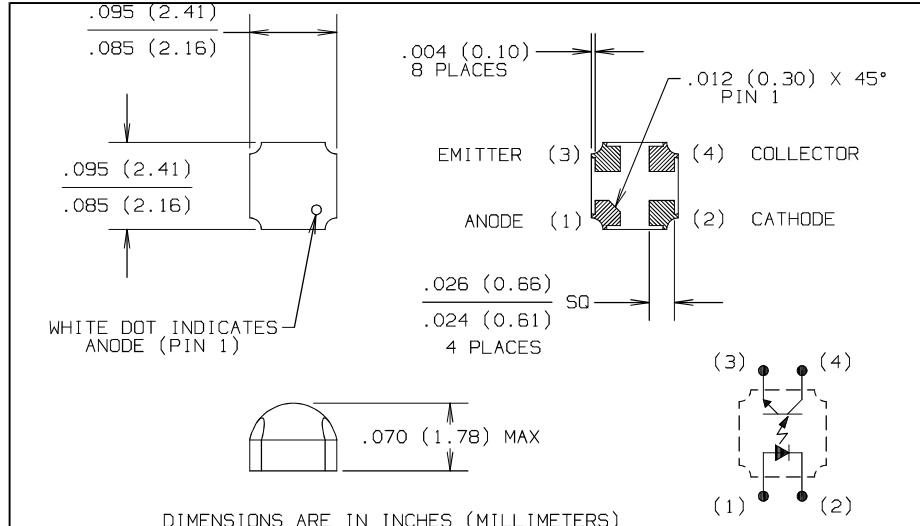


# Surface Mount Optically Coupled Isolators

## Types OPI210, OPI211



### Features

- Micro-miniature package ideal for hybrid applications
- TTL, DTL compatible
- High DC current transfer ratio
- Four bonding pads for attaching to hybrid substrates
- 1kV electrical isolation
- High efficiency gallium aluminum arsenide emitter

### Description

The OPI210 and OPI211 are optically coupled isolators each consisting of a gallium aluminum arsenide LED and a silicon phototransistor mounted and coupled on a thick film ceramic substrate. These solid-state optocouplers are ideal for hybrid applications. Four thick film bonding pads make electrical connections easy.

The OPI210 and OPI211 are identical except for the DC current transfer ratio. Both were designed with high reliability in mind and are ideally suited for use in MIL-STD-883 hybrid applications.

Device mounting may be achieved using silver or gold filled epoxies. The OPI210 and OPI211 are sensitive to some hybrid cleaning processes. Consult factory for details.

### Absolute Maximum Ratings ( $T_A = 25^\circ C$ unless otherwise noted)

Input-to-Output Isolation Voltage.....	$\pm 1000$ VDC <sup>(1)</sup>
Storage Temperature Range.....	-65° C to +150° C
Operating Temperature Range.....	-55° C to +125° C

#### Input Diode

Continuous Forward DC Current.....	50 mA
Peak Forward Current (1 $\mu$ s pulse width, 300 pps).....	1.00 A
Reverse Voltage .....	3.0 V
Power Dissipation.....	60 mW <sup>(2)</sup>

#### Output Sensor

Continuous Collector Current .....	50 mA
Collector-Emitter Voltage .....	35 V
Emitter-Collector Voltage.....	7.0 V
Power Dissipation.....	100 mW <sup>(3)</sup>

#### Notes:

- (1) Measured with input diode bond pads shorted together and output bond pads shorted together.
- (2) Derate linearly above 65° C free air temperature at the rate 1.0 mW/° C.
- (3) Derate linearly above 25° C free air temperature at the rate of 1.0 mW/° C.

# Types OPI210, OPI211

Electrical Characteristics ( $T_A = 25^\circ C$  unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Units	Test Conditions
<b>Input Diode</b>						
$V_F$	Forward Voltage		1.15	1.50	V	$I_F = 10.0 \text{ mA}$
$I_R$	Reverse Current		0.1	100	$\mu\text{A}$	$V_R = 2.0 \text{ V}$
<b>Output Sensor</b>						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	35	80		V	$I_C = 100 \mu\text{A}, I_F = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	7.0	10.0		V	$I_E = 100 \mu\text{A}, I_F = 0$
$I_{CEO}$	Collector-Emitter Dark Current		20	100	nA	$V_{CE} = 20 \text{ V}, I_F = 0$
<b>Coupled</b>						
$I_C/I_F$	DC Current Transfer Ratio	OPI210 OPI211	50 200	200 350	%	$V_{CE} = 5.0 \text{ V}, I_F = 10.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_F = 10.0 \text{ mA}$
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage		0.2	0.30	V	$I_C = 2.0 \text{ mA}, I_F = 20 \text{ mA}$
$t_r$ , $t_f$	Output Rise Time Output Fall Time		3.0 3.0	10.0 10.0	$\mu\text{s}$ $\mu\text{s}$	$V_{CC} = 10.0 \text{ V}, R_L = 100 \Omega$ Pulse width = 100 ms, duty cycle = 1%

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MOUNT

Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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